#### Datasheet

PNP -200mA -30V Digital Transistors (Bias Resistor Built-in Transistors)

Parameter	Value
V <sub>CC</sub>	-30V
I <sub>C(MAX.)</sub>	-200mA
R <sub>1</sub>	$4.7$ k $\Omega$
$R_2$	47kΩ

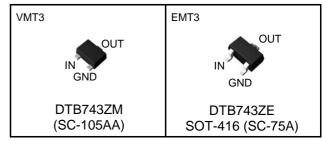
## Features

- 1) Built-In Biasing Resistors
- 2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 5) Complementary NPN Types :DTD743Z series
- 6) Lead Free/RoHS Compliant.

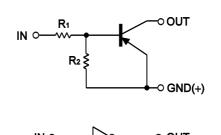
#### Application

Switching circuit, Inverter circuit, Interface circuit, Driver circuit

#### Outline



#### •Inner circuit



#### Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
DTB743ZM	VMT3	1212	T2L	180	8	8,000	Y13
DTB743ZE	EMT3	1616	TL	180	8	3,000	Y13

## ● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Values	Unit
Supply voltage	V <sub>cc</sub>	-30	V
Input voltage	V <sub>IN</sub>	−20 to +5	V
Collector current	I <sub>C(MAX.)</sub> *1	-200	mA
Power dissipation	$P_{D}^{*2}$	150	mW
Junction temperature	T <sub>j</sub>	150	°C
Range of storage temperature	T <sub>stg</sub>	-55 to +150	°C

## ●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
longet coaltana	$V_{I(off)}$	$V_{CC} = -5V, I_{O} = -100 \mu A$	-	-	-0.3	V	
Input voltage	$V_{I(on)}$	$V_0 = -0.3V, I_0 = -20mA$	-1.2	-	-	V	
Output voltage	$V_{O(on)}$	$I_0 / I_1 = -50 \text{mA} / -2.5 \text{mA}$	-	-0.07	-0.3	V	
Input current	I <sub>I</sub>	$V_1 = -5V$	-	-	-1.4	mA	
Output current	I <sub>O(off)</sub>	$V_{CC} = -30V, V_1 = 0V$	-	-	-0.5	μΑ	
DC current gain	Gı	$V_0 = -2V, I_0 = -100 \text{mA}$	140	-	-	-	
Input resistance	R <sub>1</sub>	-	3.29	4.7	6.11	kΩ	
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	-	8	10	12	-	
Transition frequency	f <sub>T</sub> *1	$V_{CE} = -10V, I_{E} = 5mA,$ f = 100MHz	ı	260	-	MHz	

<sup>\*1</sup> Characteristics of built-in transistor

<sup>\*2</sup> Each terminal mounted on a reference footprint

### ●Electrical characteristic curves(Ta = 25°C)

Fig.1 Input voltage vs. output current (ON characteristics)

-100
Vo=-0.3V

Ta= 125°C
-10
-25°C
-40°C
-0.1
-0.1
-1
-0.1
-1
-10
-100

OUTPUT CURRENT: I<sub>o</sub> [mA]

Fig.2 Output current vs. input voltage (OFF characteristics)

-100

Vo= -5V

Ta= 125°C

75°C

-55°C

-0.1

-0.1

-0.1

-0.2

INPUT VOLTAGE: V<sub>I(off)</sub>[V]

Fig.3 Output current vs. output voltage -0.9mA-0.8mA -0.7mA -200 -0.5mA -0.4mA OUTPUT CURRENT: Io [mA] -150 DC CURRENT GAIN: G -100 -0.2mA -50 Ta=25°C 0 0 -10 OUTPUT VOLTAGE : Vo [V]

1000
V<sub>0</sub>= -5V

Ta= 125°C
75°C
25°C
-40°C

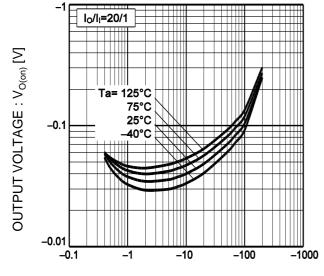
100

OUTPUT CURRENT : I<sub>0</sub> [mA]

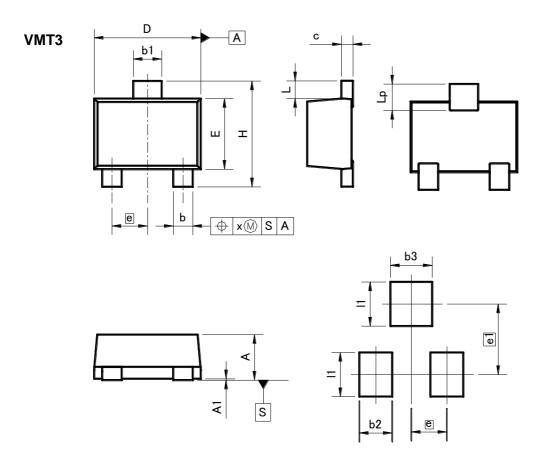
Fig.4 DC current gain vs. output current

## ●Electrical characteristic curves(Ta = 25°C)

Fig.5 Output voltage vs. output current



## ●Dimensions (Unit:mm)



### Patterm of terminal position areas

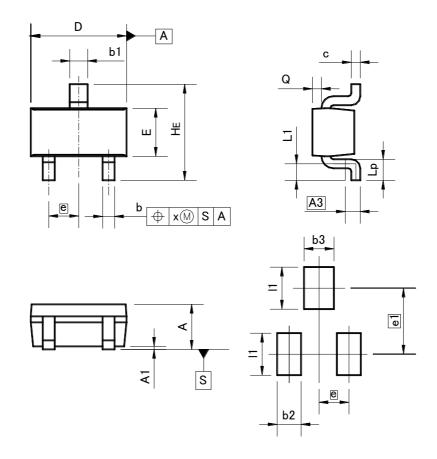
DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	0.45	0.55	0.018	0.022	
A1	0.00	0.10	0	0.004	
b	0.17	0.27	0.007	0.011	
b1	0.27	0.37	0.011	0.015	
С	0.08	0.18	0.003	0.007	
D	1.10	1.30	0.043	0.051	
Е	0.70	0.90	0.028	0.035	
е	0.4	40	0.0	02	
HE	1.10	1.30	0.043	0.051	
L	0.10	0.30	0.004		
Lp	0.20	0.40	0.008	-	
x	_	0.10	_	0.004	

DIM	MILIMETERS		INCHES		
DIIVI	MIN	MAX	MIN	MAX	
e1	0.80		0.03		
b2	_	0.37	ı	0.015	
b3	-	0.47	ı	0.019	
l1	_	0.50	ı	0.02	

Dimension in mm/inches

## ●Dimensions (Unit:mm)





## Patterm of terminal position areas

DIM	MILIMI	ETERS	INCHES	
DIM	MIN	MAX	MIN	MAX
Α	0.60	0.80	0.024	0.031
A1	0.00	0.10	0	0.004
A3	0.2	25	0.01	
b	0.15	0.30	0.006	0.012
b1	0.25	0.40	0.01	0.016
С	0.10	0.20	0.004	0.008
D	1.50	1.70	0.059	0.067
E	0.70	0.90	0.028	0.035
е	0.50		0.02	
HE	1.40	1.80	0.055	0.071
L1	0.10	ı	0.004	-
Lp	0.15		0.006	_
Q	0.05	0.25	0.002	0.01
Х	_	0.10	_	0.004

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
e1	1.10		0.04		
b2	-	0.40	-	0.016	
b3	-	0.50	-	0.02	
11	_	0.70	_	0.028	

Dimension in mm/inches

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